UNISONIC TECHNOLOGIES CO., LTD

UTG60N65FQ-S

Preliminary

Insulated Gate Bipolar Transistor

650V TRENCH GATE FIELD-STOP IGBT

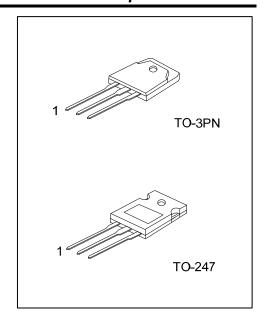
■ DESCRIPTION

The UTC **UTG60N65FQ-S** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

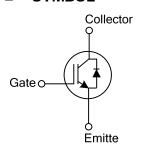
The UTC **UTG60N65FQ-S** is suitable for the resonant or soft switching applications.

■ FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: V_{CE(SAT).Typ.}=1.64V @ I_C=60A, V_{GE}=15V (T_C =25°C)



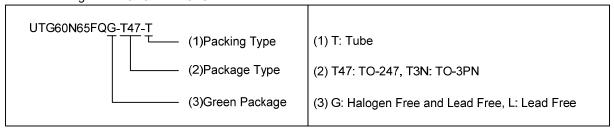
■ SYMBOL



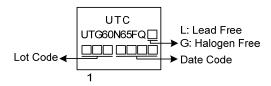
ORDERING INFORMATION

Ordering Number		Daalsana	Pin	Assignm	Daakina		
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTG60N65FQL-T47-T	UTG60N65FQG-T47-T	TO-247	G	C	Е	Tube	
UTG60N65FQL-T3N-T	UTG60N65FQG-T3N-T	TO-3PN	G	С	E	Tube	

Note: Pin Assignment: G: Gate C: Collector E: Emitter



MARKING



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■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise noted)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage		V _{CES}	650	V
Gate-Emitter Voltage			±20	V
Transient Gate-emitter voltage (tp < 5 ms)		V_{GES}	±25	V
Continuous Collector Current	T _C =25°C	<u>ا</u>	120	Α
	T _C =100°C		60	Α
Collector Current Pulsed (Note 1)		I _{CM}	240	Α
Diode Forward Current	T _C =25°C	l _F	72	Α
	T _C =100°C		36	Α
Short Circuit Withstand Time		tsc		
$V_{\rm GE} = 15 \text{V}, \ V_{\rm CC} \le 200 \text{V}$				μs
Allowed number of short circuits < 1000			3	
Time between short circuits: ≥1.0s T _{VJ} = 25°C				
Power Dissipation (Tc=25°C)	TO-247	P _D	285	W
	TO-3P		310	W
Operating Junction Temperature		TJ	-40 ~ +175	°C
Storage Temperature Range		T _{STG}	-55 ~ +175	°C

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

■ THERMAL DATA

PARAMETER		SYMBOL	RATING	UNIT	
l ti t- O	TO-247	0	0.44	°C/W	
Junction to Case	TO-3P	Alc	0.4	°C/W	

^{2.} Pulse width limited by maximum junction temperature.

■ ELECTRICAL CHARACTERISTICS (Tc=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Off Characteristics	-	•	_	I	I	ı	
Collector-Emitter Breakdown Voltage	BV _{CES}			650			V
Collector Cut-Off Current	I _{CES}	V _{CE} =650V, V _{GE} =0V				5	μΑ
G-E Leakage Current	I _{GES}	V _{CE} =0V, V _{GE} =±20V				±400	nA
On Characteristics							
Gate to Emitter Threshold Voltage	$V_{\text{GE(TH)}}$	I _C =250μA, V _{CE} =V _{GE}		4.5		7.5	V
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =60A, V _{GE} =15V	T _C =25°C		1.64	2.1	V
			T _C =125°C		2.0		V
Dynamic Characteristics				ā.	ā.		
Input Capacitance	CIES	V _{CE} =25V, V _{GE} =0V, f=1MHz			2690		рF
Output Capacitance	Coes				194		рF
Reverse Transfer Capacitance	C _{RES}				38.8		рF
Switching Characteristics							
Total Gate Charge	Q_{G}	V _{CE} =600V, I _C =60A, V _{GE} =15V			121		nC
Gate-Emitter Charge	Q_GE				32.8		nC
Gate-Collector Charge	Q_GC				56.8		nC
Turn-On Delay Time	t _{DON)}				19		ns
Rise Time	t_{R}				73		ns
Turn-Off Delay Time	t _{DOFF)}	V _{CC} =600V, I _C =60A, R _G =5Ω, V _{GE} =0~15V, L=500uH			89		ns
Fall Time	t_{F}				119		ns
Turn-On Switching Loss	Eon				3.02		mJ
Turn-Off Switching Loss	E _{OFF}				1.7		mJ
SOURCE- DRAIN DIODE RATINGS A	ND CHARAC	TERISTICS					
Forward Voltage Drop	VF	I _F =30A				2.5	V
Reverse Recovery Time	t _{rr}	-I _F =60A, dI/dt=100A/μS, V _{CC} =400V			31.7		ns
Reverse Recovery Charge	Q_{rr}				127		nC

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